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Vishay Siliconix

Automotive P-Channel 60 V (D-S) MOSFET



Marking Code: 9D

PRODUCT SUMMARY					
V _{DS} (V)	-60				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.290				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.395				
I _D (A)	-1.6				
Configuration	Single				
Package	SC-70				

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Typical ESD protection: 800 V
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

	(1, 2, 5, 6) D
(3) G O	
P-Channel MOSFET	
	(4) S

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V_{DS}	-60		
Gate-source voltage		V_{GS}	± 20	V	
Continuous drain current	T _C = 25 °C a	1	-1.6		
	T _C = 125 °C		-1		
Continuous source current (diode conduction	I _S	-1.6	А		
Pulsed drain current ^b		I _{DM}		-6.7	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-8		
Single pulse avalanche energy	L = U.1 IIIII	E _{AS}	3.2	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D	2.7	W	
	T _C = 125 °C	P_{D}	0.5	VV	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient PC	CB mount c	R _{thJA}	125	°C/W	
Junction-to-foot (drain)		R _{thJF}	45	- C/W	

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)



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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static		•						
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$		-60	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$		-2.0	-2.5]	
Onto anima lankana		V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$		-	± 5	μA	
Gate-source leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 5	mA	
		$V_{GS} = 0 V$	$V_{DS} = -60 \text{ V}$	-	-	-1		
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -60 V, T _J = 125 °C	-	-	-50	μA	
		V _{GS} = 0 V	V _{DS} = -60 V, T _J = 150 °C	-	-	-150		
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 V$	-5	-	-	Α	
Drain-source on-state resistance ^a		V _{GS} = -10 V	I _D = -2 A	-	0.230	0.290		
	Ь	V _{GS} = -10 V	I _D = -2 A, T _J = 125 °C	-	-	0.470		
	R _{DS(on)}	V _{GS} = -10 V	I _D = -2 A, T _J = 150 °C	-	-	0.566	Ω	
		V _{GS} = -4.5 V	I _D = -1 A	-	0.305	0.395		
Forward transconductance b	9 _{fs}	V _{DS} =	-10 V, I _D = -1.5 A	-	3	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			-	284	355		
Output capacitance	Coss	$V_{GS} = 0 V$	0 V V _{DS} = -25 V, f = 1 MHz		36	45	pF	
Reverse transfer capacitance	C _{rss}			-	28	35		
Total gate charge ^c	Qg			-	3.6	5.4		
Gate-source charge ^c	Q _{gs}	$V_{GS} = -4.5 \text{ V}$	$V_{GS} = -4.5 \text{ V}$ $V_{DS} = -30 \text{ V}, I_{D} = -1 \text{ A}$		1.2	-	nC	
Gate-drain charge ^c	Q_{gd}	1		-	1.7	-		
Gate resistance	R _g	f = 1 MHz		3.1	6.05	9	Ω	
Turn-on delay time ^c	t _{d(on)}			-	44	66		
Rise time ^c	t _r	V_{DD} = -30 V, R_L = 30 Ω $I_D \cong$ -1 A, V_{GEN} = -4.5 V, R_g = 1 Ω		-	25	38		
Turn-off delay time ^c	t _{d(off)}			-	13	20	ns -	
Fall time ^c	t _f			ı	9	14		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	-6.7	А	
Forward voltage	V_{SD}	I _F = ·	-	-0.8	-1.2	V		

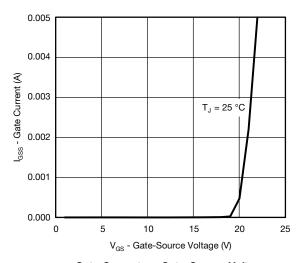
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

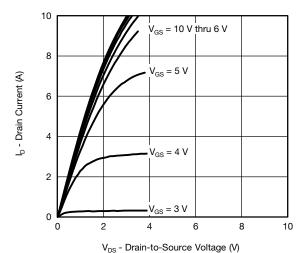
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



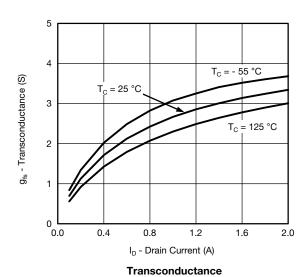
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

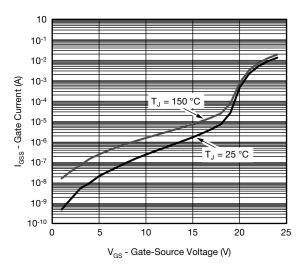


Gate Current vs. Gate-Source Voltage

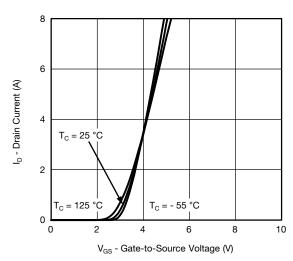


Output Characteristics

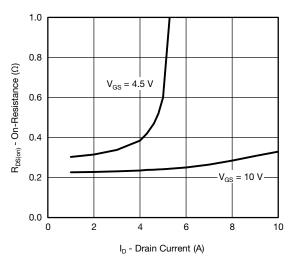




Gate Current vs. Gate-Source Voltage



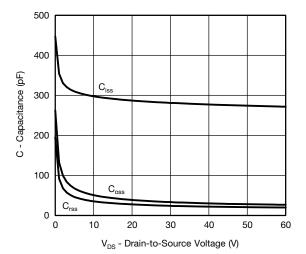
Transfer Characteristics



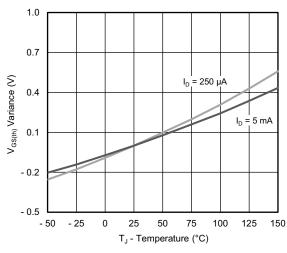
On-Resistance vs. Drain Current



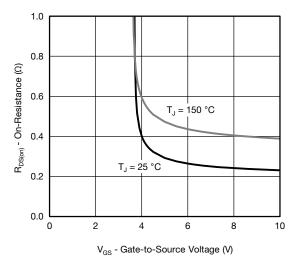
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



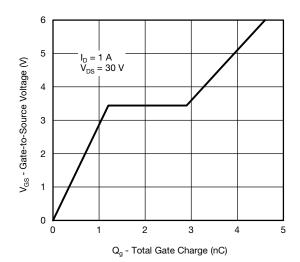
Capacitance



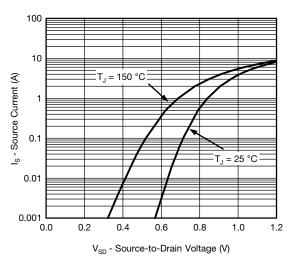
Threshold Voltage



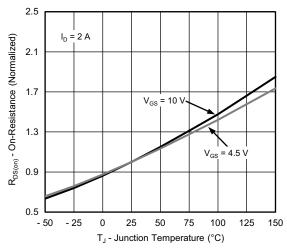
On-Resistance vs. Gate-to-Source Voltage



Gate Charge



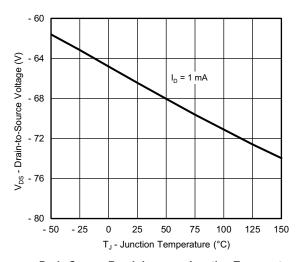
Source Drain Diode Forward Voltage



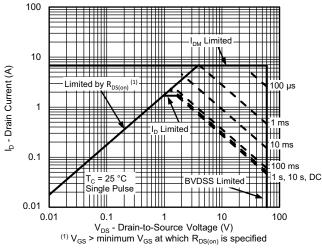
On-Resistance vs. Junction Temperature



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



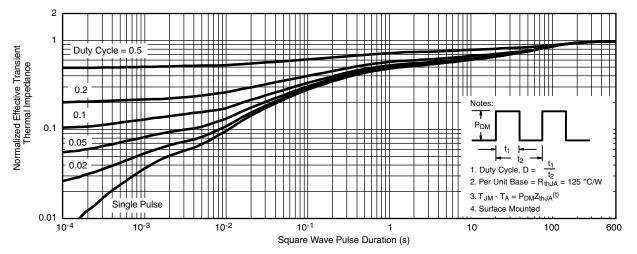
Drain Source Breakdown vs. Junction Temperature



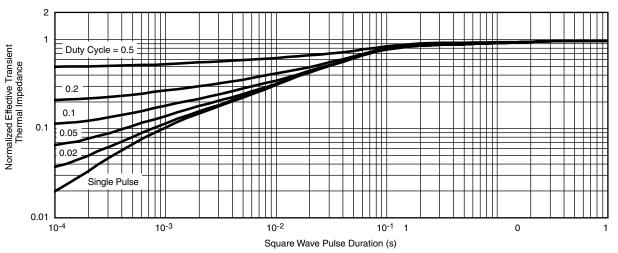
Safe Operating Area



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

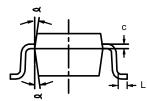
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SC-70: 6-LEADS



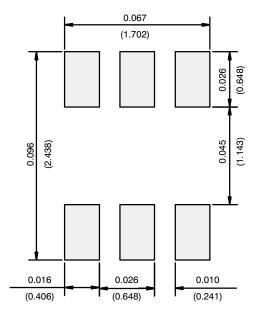


	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	-	1.10	0.035	-	0.043
A ₁	_	-	0.10	_	_	0.004
A ₂	0.80	-	1.00	0.031	_	0.039
b	0.15	-	0.30	0.006	_	0.012
С	0.10	-	0.25	0.004	-	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Е	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC			0.026BSC		
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
۵	7°Nom				7°Nom	
ECN: S-03946—Rev. B, 09-Jul-01						

DWG: 5550



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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